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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SK4212

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK4212 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

FEATURES

- Low on-state resistance
- $R_{DS(on)1}$ = 7.8 m Ω MAX. (V_{GS} = 10 V, I_D = 30 A)
- $R_{DS(on)2}$ = 14 m Ω MAX. (V_{GS} = 4.5 V, I_D = 20 A)
- Low total gate charge

QG = 27 nC TYP. (VDD = 15 V, VGS = 10 V, ID = 30 A)

- 4.5 V drive available
- Avalanche capability ratings

ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
2SK4212-ZK-E1-AY Note			TO 252 (MD 27K) hm 0.27 m
2SK4212-ZK-E2-AY Note	Pure Sn (Tin)	Tape 2500 p/reel	TO-252 (MP-3ZK) typ. 0.27 g

Note Pb-free (This product does not contain Pb in external electrode).

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Drain to Source Voltage (V _{GS} = 0 V)	VDSS	25	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±48	Α
Drain Current (pulse) Note1	D(pulse)	±144	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	35	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C
Single Avalanche Current Note2	las	17	Α
Single Avalanche Energy Note2	Eas	28.9	mJ

(TO-252)



Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting Tch = 25°C, VDD = 12.5 V, RG = 25 $\Omega,$ VGS = 20 \rightarrow 0 V, L = 0.1 mH

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CHARACTERISTICS	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 25 V, V _{GS} = 0 V			10	μA
Gate Leakage Current	Igss	V _{GS} = ±16 V, V _{DS} = 0 V			±100	nA
Gate to Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	1.5		3.0	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 5 V, I _D = 12 A	10	22		S
Drain to Source On-state Resistance ^{Note}	RDS(on)1	V _{GS} = 10 V, I _D = 30 A		5.5	7.8	mΩ
	RDS(on)2	V _{GS} = 4.5 V, I _D = 20 A		8.5	14	mΩ
Input Capacitance	Ciss	V _{DS} = 15 V,		1200		pF
Output Capacitance	Coss	V _{GS} = 0 V,		220		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		140		pF
Turn-on Delay Time	td(on)	Vdd = 15 V, Id = 30 A,		16		ns
Rise Time	tr	Vgs = 10 V,		14		ns
Turn-off Delay Time	td(off)	R _G = 3 Ω		45		ns
Fall Time	tr			11		ns
Total Gate Charge	QG	V _{DD} = 15 V,		27		nC
Gate to Source Charge	Q _{GS}	V _{GS} = 10 V,		4		nC
Gate to Drain Charge	Qgd	ID = 30 A		7		nC
Body Diode Forward Voltage Note	VF(S-D)	I⊧ = 30 A, V₀s = 0 V		0.88	1.5	V
Reverse Recovery Time	trr	I⊧ = 30 A, V₀s = 0 V,		26		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs		14		nC

Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

TEST CIRCUIT 2 SWITCHING TIME

D.U.T.

١ΛΛ

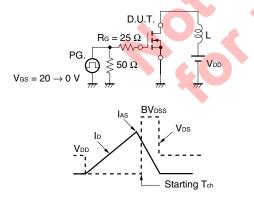
Rg

PG.

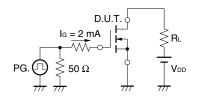
τ

 $\tau = 1 \ \mu s$ Duty Cycle $\leq 1\%$

V_{GS} 0 —



TEST CIRCUIT 3 GATE CHARGE



Vgs ≶R∟ VGS Wave Form 90% 0 10% Vgs VDD Vds 90% 90% VDS VDS Wave Form 10 0 td(on) tr td(off) tſ ton toff

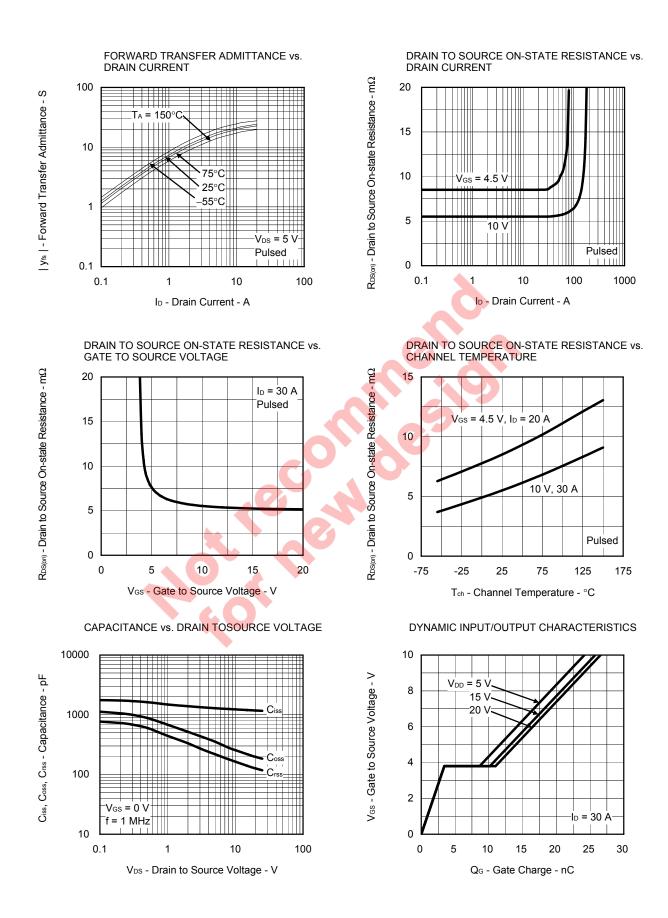
TYPICAL CHARACTERISTICS (TA = 25°C) DERATING FACTOR OF FORWARD BIAS FORWARD BIAS SAFE OPERATING AREA SAFE OPERATING AREA 120 1000 dT - Percentage of Rated Power - % 100 100 Ip - Drain Current - A 80 60 10 40 1 ms 1 20 10 ms Tc = 25°C Single Puls 0 0.1 0 25 50 75 100 125 150 175 0.01 0.1 1 10 100 Vps - Drain to Source Voltage - V Tc - Case Temperature - °C TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH 1000 +++ r_{th(t)} - Transient Thermal Resistance - °C/W $R_{th(ch-A)} = 125^{\circ}C/W$ 100 4 10 $R_{th(ch-C)} = 3.57$ C/W # 1 Ħ 0.1 Single Pulse 0.01 100 µ 1 m 10 m 100 m 1 10 100 1000 PW - Pulse Width - s FORWARD TRANSFER CHARACTERISTICS GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE V_{GS(th)} - Gate to Source Threshold Voltage - V 30 4 3 Ip - Drain Current - A 20 T_A = 125°C 75°C 2 25°C -55°C 10 1 V_{DS} = 10 VDS = VGS Pulsed I_D = 250 μA 0 0 0 1 2 3 4 5 -75 -25 25 75 125 175

Data Sheet D19564EJ1V0DS

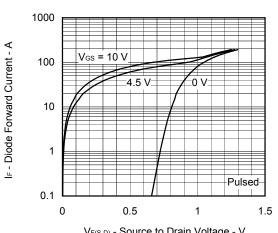
VGS - Gate to Source Voltage - V

3

Tch - Channel Temperature - °C



NEC



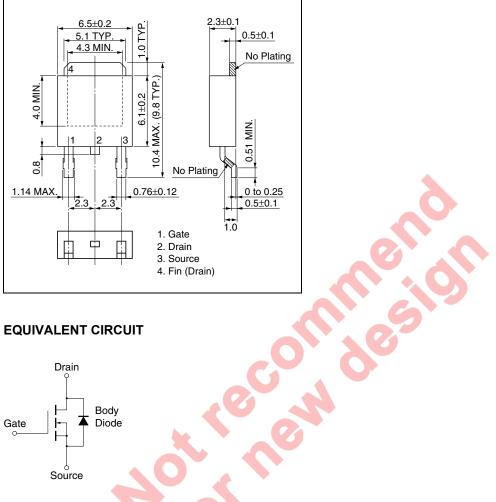
SOURCE TO DRAIN DIODE FORWARD VOLTAGE

Vr(s-b) - Source to Drain Voltage - V

Data Sheet D19564EJ1V0DS

PACKAGE DRAWINGS (Unit: mm)





Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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